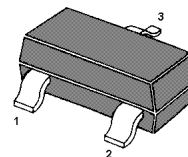


S9014 TRANSISTOR (NPN)

FEATURES

Complementary to S9015

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

MARKING: J6

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	value	units
V_{CB0}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	0.1	A
P_C	Collector Power Dissipation	0.2	W
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature	-55-150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CB0}$	$I_C=100\mu\text{A}$, $I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=0.1\text{mA}$, $I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}$, $I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=50\text{V}$, $I_E=0$			0.1	μA
Collector cut-off current	I_{CEO}	$V_{CE}=35\text{V}$, $I_B=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=3\text{V}$, $I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=5\text{V}$, $I_C=1\text{mA}$	200		450	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=100\text{mA}$, $I_B=5\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=100\text{mA}$, $I_B=5\text{mA}$			1	V
Transition frequency	f_T	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$ $f=30\text{MHz}$	150			MHz

电话: 0755-82568882 82568883

邮箱: idchip@indreamchip.com

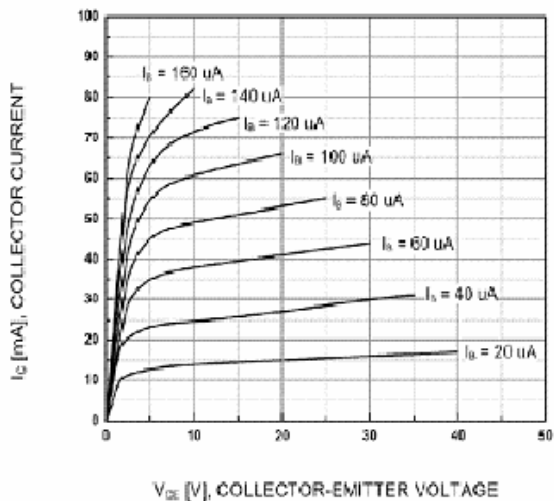
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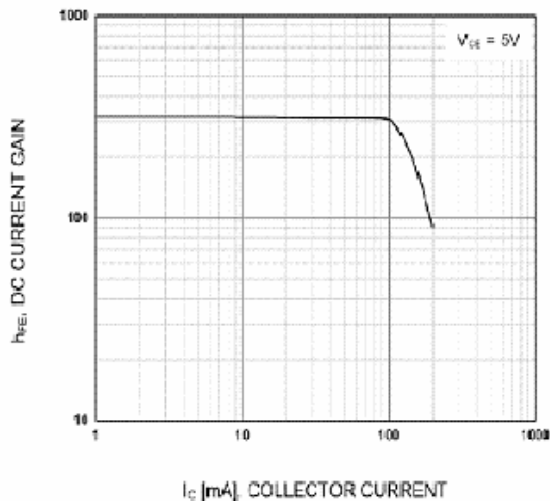
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Typical Characteristics

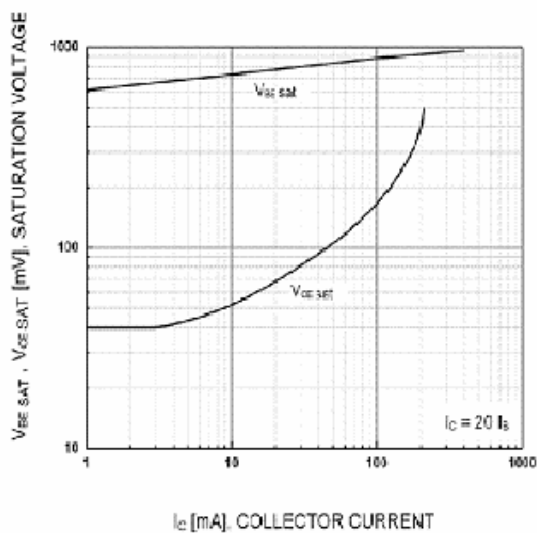
S9014



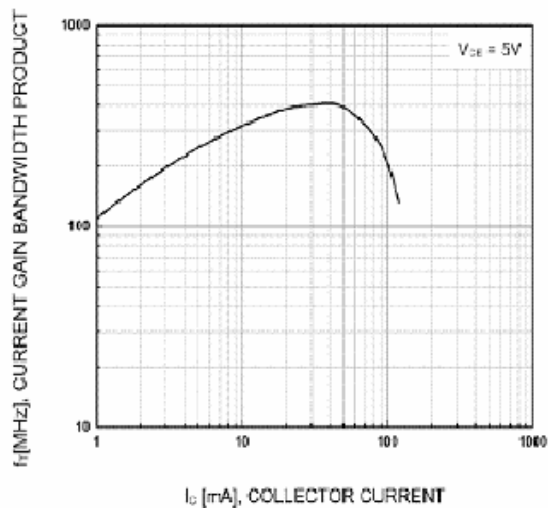
Static Characteristic



DC current Gain



Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage



Current Gain Bandwidth Product

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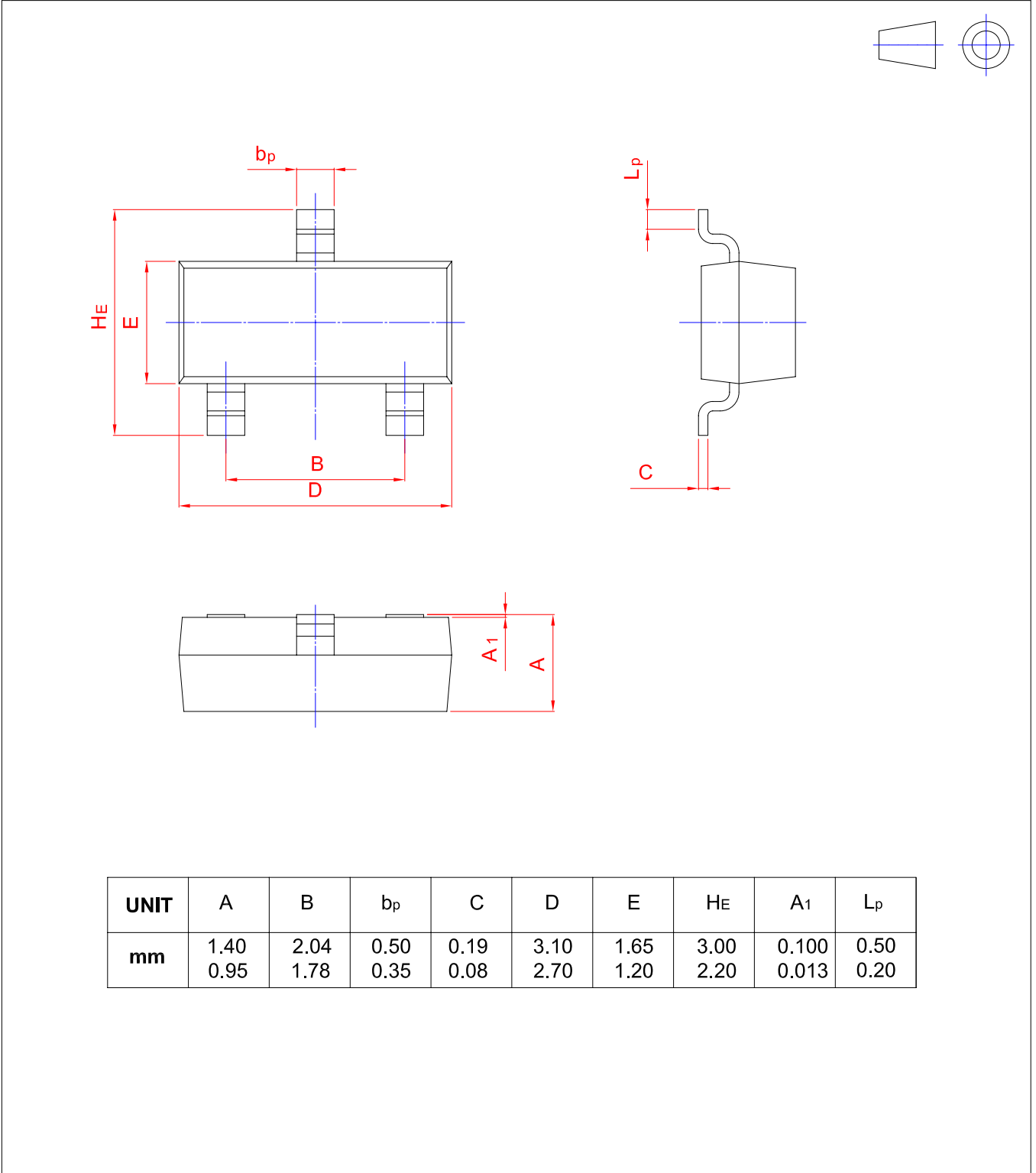
邮箱: idchip@indreamchip.com

网址: www.idchip.cn

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



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